

isc N-Channel MOSFET Transistor

FDP26N40

• FEATURES

- · With TO-220 packaging
- · High speed switching
- · Low gate input resistance
- · Standard level gate drive
- · Easy to use
- · 100% avalanche tested
- Minimum Lot-to-Lot variations for robust device performance and reliable operation



APPLICATIONS

- Power supply
- · Switching applications

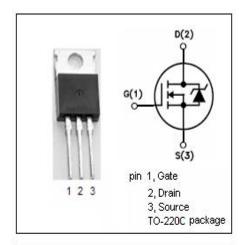


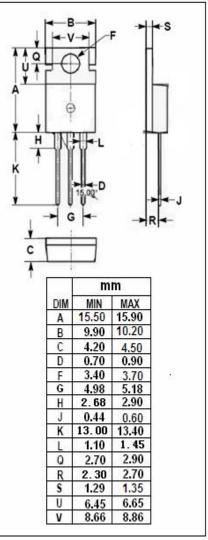
• ABSOLUTE MAXIMUM RATINGS(Ta=25°C)

SYMBOL	PARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage	400	V
V _{GSS}	Gate-Source Voltage	±30	V
I _D	Drain Current-Continuous;@Tc=25°C Tc=100°C	26 15.6	А
I_{DM}	Drain Current-Single Pulsed	104	А
P _D	Total Dissipation	265	W
Tj	Operating Junction Temperature	150	${\mathbb C}$
T _{stg}	Storage Temperature	-55~150	$^{\circ}$



SYMBOL	PARAMETER		UNIT		
Rth(ch-c)	Channel-to-case thermal resistance	e thermal resistance 0.5			
Rth(ch-a)	Channel-to-ambient thermal resistance	62.5	°C/W		





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ELECTRICAL CHARACTERISTICS

T_C=25℃ unless otherwise specified

SYMBOL	PARAMETER	CONDITIONS	MIN	ТҮР	MAX	UNIT
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V; I _D = 0.25mA	400			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} ; I _D =0.25mA	3.0		5.0	V
R _{DS(on)}	Drain-Source On-Resistance	V _{GS} = 10V; I _D =13A		130	160	mΩ
I _{GSS}	Gate-Source Leakage Current	V _{GS} =±20V;V _{DS} = 0V			±0.1	μА
I _{DSS}	Drain-Source Leakage Current	V _{DS} = 400V; V _{GS} = 0V;Tj=25°C V _{DS} = 320V; V _{GS} = 0V;Tj=125°C			1 10	μА
V _{SDF}	Diode forward voltage	I _{SD} =24A, V _{GS} = 0 V			1.4	V

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